## FEATURES

- HIGH VOLTAGE - 400V ( $\pm 200 \mathrm{~V}$ )
- LOW QUIESCENT CURRENT - 10mA
- HIGH OUTPUT CURRENT - 4A
- PROGRAMMABLE CURRENT LIMIT


## APPLICATIONS

- PIEZOELECTRIC POSITIONING
- HIGH VOLTAGE INSTRUMENTATION
- ELECTROSTATIC TRANSDUCERS
- PROGRAMMABLE POWER SUPPLIES UP TO 390V


## DESCRIPTION

The PA92 is a high voltage, low quiescent current MOSFET operational amplifier designed as a low cost solution for driving continuous output currents up to 4A and pulse currents up to 7A. The safe operating area (SOA) has no second breakdown limitations and can be observed for all type loads by choosing an appropriate current limiting resistor. The MOSFET output stage is biased $A B$ for linear operation. External compensation provides flexibility in choosing bandwidth and slew rate for the application. APEX's Power SIP package uses a minimum of board space allowing for high density circuit boards.

## EQUIVALENT SCHEMATIC




TYPICAL APPLICATION


## LOW POWER, PIEZOELECTRIC POSITIONING

Piezo positioning may be applied to the focusing of segmented mirror systems. The composite mirror may be composed of hundreds of elements, each requiring focusing under computer control. In such complex systems the PA92 reduces the costs of power supplies and cooling with its advantages of low cost and low quiescent power consumption while increasing circuit density with the SIP package.

## PHASE COMPENSATION

| $\frac{\text { GAIN }}{21}$ |  | $\mathrm{C}_{\mathrm{C}}{ }^{*}$ |  | $\mathrm{R}_{\mathrm{C}}$ |
| :---: | :---: | :---: | :---: | :---: |
|  |  | 150 pF |  | $100 \Omega$ |
| $\geq 2$ |  | 100 pF |  | $100 \Omega$ |
| $\geq 3$ |  | 47 pF |  | $0 \Omega$ |
| $\geq 12$ |  | 10 pF |  | $0 \Omega$ |

${ }^{*} \mathrm{C}_{c}$ Never to be $<10 \mathrm{pF}$. $\mathrm{C}_{\mathrm{c}}$ To be rated for the full supply voltage +V to -Vs . Use ceramic NPO (COG) type.

EXTERNAL CONNECTIONS
Package: SIP03


## ABSOLUTE MAXIMUM RATINGS

| SUPPLY VOLTAGE, $+\mathrm{V}_{s}$ to $-\mathrm{V}_{s}$ | 400 V |
| :--- | :--- |
| OUTPUT CURRENT, source, sink, peak | 7 A, within SOA |
| POWER DISSIPATION, continuous @ $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 80 W |
| INPUT VOLTAGE, differential | $\pm 20 \mathrm{~V}$ |
| INPUT VOLTAGE, common mode | $\pm \mathrm{V}_{S}$ |
| TEMPERATURE, pin solder -10 s max | $220^{\circ} \mathrm{C}$ |
| TEMPERATURE, junction ${ }^{\circ}$ | $150^{\circ} \mathrm{C}$ |
| TEMPERATURE, storage | -65 to $+150^{\circ} \mathrm{C}$ |
| OPERATING TEMPERATURE RANGE, case | -55 to $+125^{\circ} \mathrm{C}$ |

## SPECIFICATIONS

\begin{tabular}{|c|c|c|c|c|c|}
\hline PARAMETER \& TEST CONDITIONS ${ }^{1}$ \& MIN \& TYP \& MAX \& UNITS <br>
\hline \multicolumn{6}{|l|}{INPUT} <br>
\hline OFFSET VOLTAGE, initial OFFSET VOLTAGE, vs. temperature OFFSET VOLTAGE, vs. supply OFFSET VOLTAGE, vs. time BIAS CURRENT, initial BIAS CURRENT, vs. supply OFFSET CURRENT, initial INPUT IMPEDANCE, DC INPUT CAPACITANCE COMMON MODE VOLTAGE RANGE ${ }^{3}$ COMMON MODE REJECTION, DC NOISE \& Full temperature range
$$
\begin{aligned}
& \mathrm{V}_{\mathrm{CM}}= \pm 90 \mathrm{~V} \\
& 100 \mathrm{KHz} \mathrm{BW}, \mathrm{R}_{\mathrm{S}}=1 \mathrm{~K} \Omega, \mathrm{C}_{\mathrm{C}}=10 \mathrm{pF}
\end{aligned}
$$ \& $\pm \mathrm{V}_{\mathrm{S}} \mp 15$
80 \& 2
15
10
75
200
4
50
$10^{11}$
4

98
1 \& 10
50
25
2000
500 \& mV
$\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$
$\mu \mathrm{V} / \mathrm{V}$
$\mu \mathrm{V} / \mathrm{knh}$
pA
$\mathrm{pA} / \mathrm{V}$
pA
$\Omega$
pF
V
dB
$\mu \mathrm{Vrms}$ <br>
\hline \multicolumn{6}{|l|}{GAIN} <br>

\hline | OPEN LOOP, @ 15Hz |
| :--- |
| GAIN BANDWIDTH PRODUCT at 1 MHz |
| POWER BANDWIDTH |
| PHASE MARGIN | \& \[

$$
\begin{aligned}
& \mathrm{R}_{\mathrm{L}}=2 \mathrm{~K} \Omega, \mathrm{C}_{\mathrm{C}}=10 \mathrm{pF} \\
& \mathrm{R}_{\mathrm{L}}=2 \mathrm{~K} \Omega, \mathrm{C}_{\mathrm{C}} 10 \mathrm{pF} \\
& \mathrm{R}_{\mathrm{L}}=2 \mathrm{~K} \Omega, \mathrm{C}_{\mathrm{C}}=10 \mathrm{pF} \\
& \text { Full temperature range }
\end{aligned}
$$

\] \& 94 \& \[

$$
\begin{aligned}
& 111 \\
& 18 \\
& 30 \\
& 60
\end{aligned}
$$

\] \& \& \[

$$
\begin{gathered}
\mathrm{dB} \\
\mathrm{MHz} \\
\mathrm{kHz}
\end{gathered}
$$
\] <br>

\hline \multicolumn{6}{|l|}{OUTPUT} <br>

\hline VOLTAGE SWING ${ }^{3}$ CURRENT, continuous SLEW RATE, $A_{v}=100$ CAPACITIVE LOAD, $\mathrm{A}_{v}=+1$ SETTLING TIME to . $1 \%$ RESISTANCE, no load \& \[
$$
\begin{aligned}
& \mathrm{I}_{\mathrm{O}}=4 \mathrm{~A} \\
& \mathrm{C}_{\mathrm{C}}=10 \mathrm{pF} \\
& \text { Full temperature range } \\
& \mathrm{C}_{\mathrm{C}}=10 \mathrm{pF}, 2 \mathrm{~V} \text { step }
\end{aligned}
$$

\] \& \[

$$
\begin{gathered}
\pm \mathrm{V}_{\mathrm{s}} \mp 12 \\
4 \\
1
\end{gathered}
$$
\] \& $\pm V_{s} \mp 10$

50
1

10 \& \& $$
\begin{gathered}
\text { V } \\
\mathrm{A} \\
\mathrm{~V} / \mu \mathrm{s} \\
\mathrm{nf} \\
\mu \mathrm{~s} \\
\Omega
\end{gathered}
$$ <br>

\hline \multicolumn{6}{|l|}{POWER SUPPLY} <br>

\hline | VOLTAGE ${ }^{5}$ |
| :--- |
| CURRENT, quiescent, | \& See note 5 \& $\pm 50$ \& \[

$$
\begin{gathered}
\pm 150 \\
10
\end{gathered}
$$

\] \& \[

$$
\begin{gathered}
\pm 200 \\
14
\end{gathered}
$$

\] \& \[

\underset{\mathrm{mA}}{\mathrm{~V}}
\] <br>

\hline THERMAL \& \& \& \& \& <br>

\hline RESISTANCE, AC, junction to case ${ }^{4}$ RESISTANCE, DC, junction to case RESISTANCE, junction to air TEMPERATURE RANGE, case \& Full temperature range, $\mathrm{F}>60 \mathrm{~Hz}$ Full temperature range, $\mathrm{F}<60 \mathrm{~Hz}$ Full temperature range Meets full range specifications \& -25 \& 30 \& \[
$$
\begin{gathered}
1 \\
1.5 \\
+85
\end{gathered}
$$

\] \& | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| :--- |
| ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| ${ }^{\circ} \mathrm{C}$ | <br>

\hline
\end{tabular}

NOTES: 1. Unless otherwise noted: $T_{C}=25^{\circ} \mathrm{C}, \mathrm{DC}$ input specifications are $\pm$ value given. Power supply voltage is typical rating. $R_{C}=100$ $\mathrm{C}_{\mathrm{C}}=150 \mathrm{pF}$.
2. Long term operation at the maximum junction temperature will result in reduced product life. Derate internal power dissipation to achieve high MTTF.
3. $+\mathrm{V}_{\mathrm{S}}$ and $-\mathrm{V}_{\mathrm{S}}$ denote the positive and negative power supply rail respectively.
4. Rating applies if the output current alternates between both output transistors at a rate faster than 60 Hz .
5. Derate max supply rating $.625 \mathrm{~V} /{ }^{\circ} \mathrm{C}$ below $25^{\circ} \mathrm{C}$ case. No derating needed above $25^{\circ} \mathrm{C}$ case.

## CAUTION

[^0]


## GENERAL

Please read Application Note 1 "General Operating Considerations" which covers stability, supplies, heat sinking, mounting, current limit, SOA interpretation, and specification interpretation. Visit www.apexmicrotech.com for design tools that help automate tasks such as calculations for stability, internal power dissipation, current limit; heat sink selection; Apex's complete Application Notes library; Technical Seminar Workbook; and Evaluation Kits.

## CURRENT LIMIT

For proper operation, the current limit resistor ( $\mathrm{R}_{\mathrm{CL}}$ ) must be connected as shown in the external connection diagram. For optimum reliability the resistor value should be set as high as possible. The value is calculated as follows; with the maximum practical value of 16 ohms.

$$
\mathrm{R}_{\mathrm{CL}}=\frac{.65}{\mathrm{I}_{\mathrm{LIM}}}
$$

## SAFE OPERATING AREA (SOA)

The MOSFET output stage of this power operational amplifier has two distinct limitations:

1. The current handling capability of the MOSFET geometry and the wire bonds.
2. The junction temperature of the output MOSFETs.

NOTE: The output stage is protected against transient flyback. However, for protection against sustained, high energy flyback, external fast-recovery diodes should be used.

## SAFE OPERATING CURVES

The safe operating area curves define the maximum additional internal power dissipation the amplifier can tolerate when it produces the necessary output to drive an external load.


## INPUT PROTECTION

Although the PA92 can withstand differential voltages up to $\pm 20 \mathrm{~V}$, additional external protection is recommended. Low leakage, low capacitance JFETs connected as diodes are recommended (e.g. 2N4416, Q1-Q4 in Figure 2). The differential input voltage will be clamped to $\pm 1.4 \mathrm{~V}$. This is sufficient overdrive to produce maximum power bandwidth.

## POWER SUPPLY PROTECTION

Unidirectional zener diode transient suppressors are recommended as protection on the supply pins. See Figure 2. The zeners clamp transients to voltages within the power supply rating and also clamp power supply reversals to ground. Whether the zeners are used or not, the system power supply should be evaluated for transient performance including poweron overshoot and power-off polarity reversals as well as line regulation.

Conditions which can cause open circuits or polarity reversals on either power supply rail should be avoided or protected against. Reversals or opens on the negative supply rail is known to induce input stage failure. Unidirectional transzorbs prevent this, and it is desirable that they be both electrically and physically as close to the amplifier as possible.

## STABILITY

The PA92 is externally compensated and performance can be tailored to the application. Use the graphs of small signal response and power response as a guide. The compensation capacitor $\mathrm{C}_{\mathrm{C}}$ must be rated at 500 V working voltage. An NPO capacitor is recommended. The compensation network $C_{c} R_{C}$ must be mounted closely to the amplifier pins 4 and 5 to avoid spurious oscillation.

## QUIESCENT CURRENT REDUCTION

When pin $3\left(I_{Q}\right)$ is shorted to pin 5 (CC2) the AB biasing of the output stage is disabled. This lowers quiescent power but also raises distortion since the output stage is then class C biased. The output stage bias current is nominally set at 1 mA . Pin 3 may be left open if not used.



[^0]:    The PA92 is constructed from MOSFET transistors. ESD handling procedures must be observed.

